

## N-Channel 30V (D-S) MOSFET

PRODUCT SUMMARY		
V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (Ω)	I <sub>D</sub> (A) <sup>a</sup>
30	0.0039 at V <sub>GS</sub> = 10 V	30.5
	0.0055 at V <sub>GS</sub> = 4.5 V	25.6

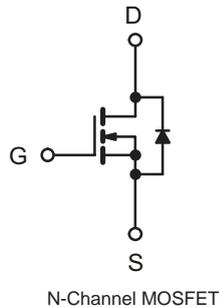
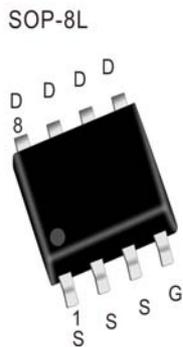
### Features

- Low Gate Charge
- RoHS Compliant

### Applications

- Low-Side DC/DC Conversion
  - Notebook PC
  - Gaming

### Pin Configuration



### Packing Information

Device	Marking	Reel Size	Tape Width	Quantity
EC4166	13D .XXX	12"	13mm	3000pcs

### Absolute Maximum Ratings (T<sub>J</sub>=25 °C Unless Otherwise Noted)

Symbol	Parameter	Value	Unit
<b>P-MOSFET</b>			
V <sub>DS</sub>	Drain-Source Voltage	30	V
V <sub>GS</sub>	Gate-Source Voltage	±20	V
I <sub>D</sub>	Continuous Drain Current	30.5	A
I <sub>DM</sub>	Pulse Drain Current	70	A
P <sub>D</sub>	Maximum Power Dissipation	5.9	W
T <sub>j</sub>	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature	-55~+150	°C
T <sub>L</sub>	Lead Temperature for Soldering Purposes(1/8" from case for 10 s)	260	°C
<b>Thermal Resistance Ratings</b>			
R <sub>thJA</sub>	Maximum Junction-to-Ambient	t ≤ 10 s	°C/W
R <sub>thJF</sub>	Maximum Junction-to-Foot (Drain)	Steady State	°C/W

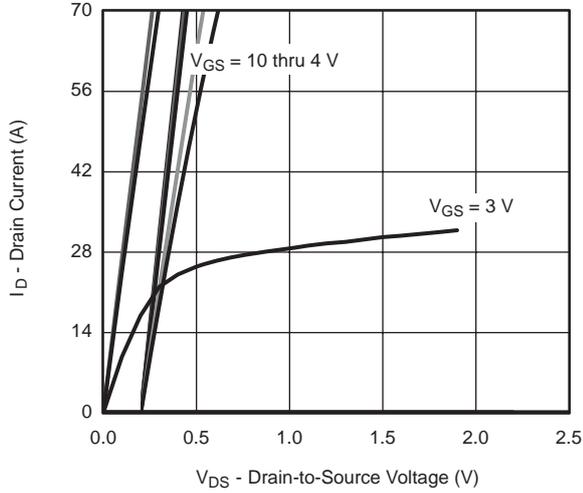
Notes:

a. Based on T<sub>C</sub> = 25 °C.

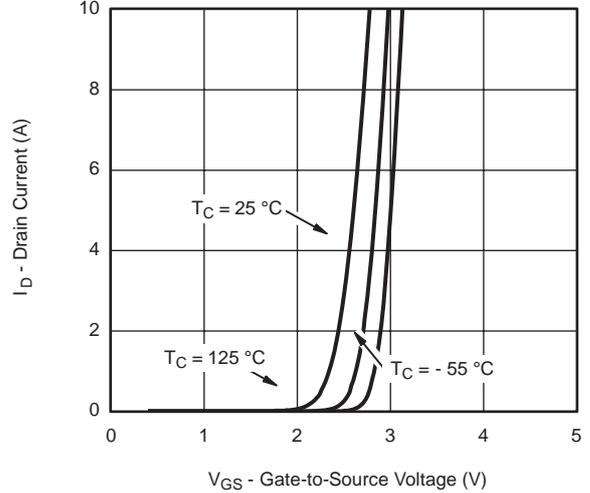
**Electrical Characteristics** ( $T_J = 25^\circ\text{C}$  Unless Otherwise Specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
<b>STATIC PARAMETERS</b>						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250 \mu A$	30			V
Zero gate voltage drain current	$I_{DSS}$	$V_{DS} = 30V, V_{GS} = 0V$			1	$\mu A$
Gate-body leakage current	$I_{GSS}$	$V_{GS} = \pm 20V, V_{DS} = 0V$			$\pm 100$	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.2		2.4	V
Drain-source on-resistance(note1)	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 15A$		3.2	3.9	$m\Omega$
		$V_{GS} = 4.5V, I_D = 10A$		4.5	5.5	$m\Omega$
Forward transconductance(note1)	$g_{FS}$	$V_{DS} = 15V, I_D = 15A$		65		S
Diode forward voltage(note1)	$V_{SD}$	$I_S = 3A, V_{GS} = 0V$		0.74	1.1	V
<b>DYNAMIC</b>						
Input capacitance	$C_{iss}$	$V_{DS} = 15V, V_{GS} = 0V, f = 1MHz$		2730		pF
Output capacitance	$C_{oss}$			540		pF
Reverse transfer capacitance	$C_{rss}$			205		pF
<b>SWITCHING PARAMETERS (note 2)</b>						
Turn-on delay time	$t_{d(on)}$	$V_{GS} = 4.5V, V_{DD} = 15V,$ $R_L = 1.5\Omega, R_G = 1\Omega, I_D = 10A$		30	50	ns
Turn-on rise time	$t_r$			19	35	ns
Turn-off delay time	$t_{d(off)}$			35	60	ns
Turn-off fall time	$t_f$			15	30	ns
Total Gate Charge	$Q_g$	$V_{DS} = 15V, V_{GS} = 4.5V,$ $I_D = 10A$		21.5	33	nC
Gate-Source Charge	$Q_{gs}$			6.9		nC
Gate-Drain Charge	$Q_{gd}$			7.1		nC

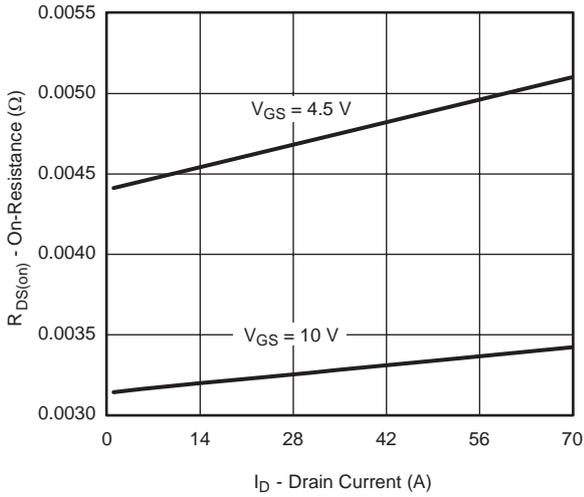
**MOSFET TYPICAL CHARACTERISTICS (25°C, unless otherwise noted)**



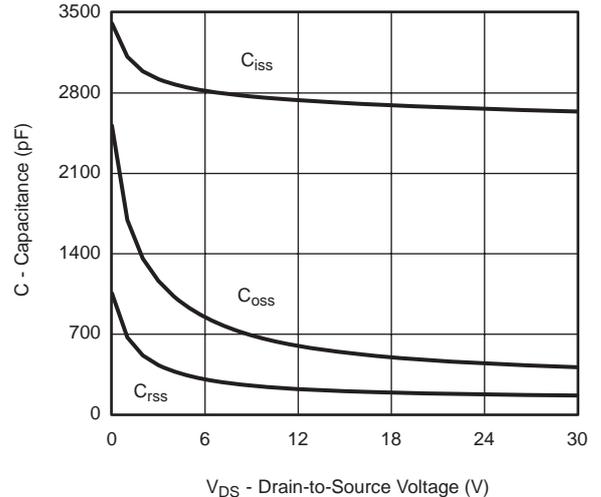
**Output Characteristics**



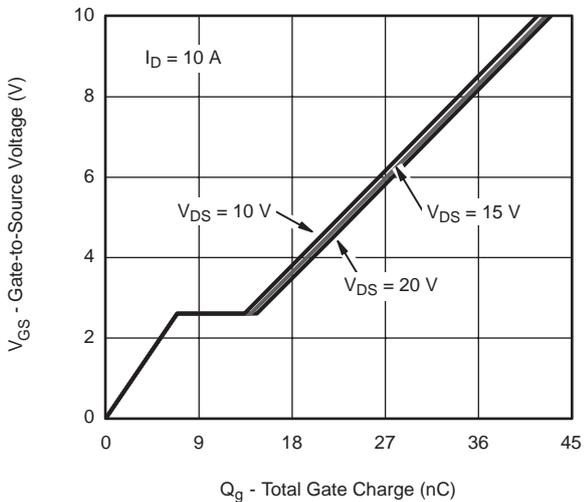
**Transfer Characteristics**



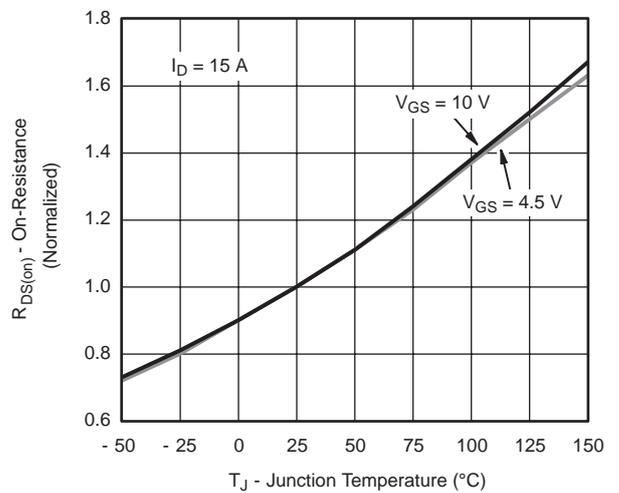
**On-Resistance vs. Drain Current and Gate Voltage**



**Capacitance**

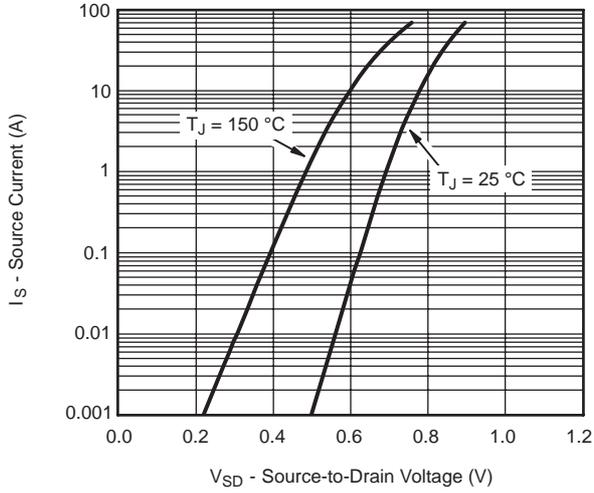


**Gate Charge**

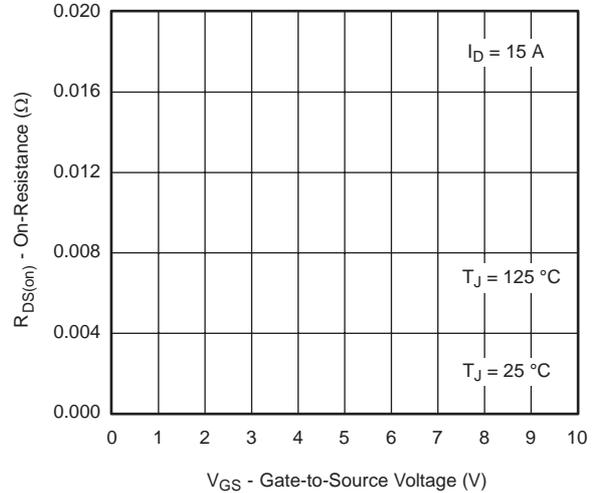


**On-Resistance vs. Junction Temperature**

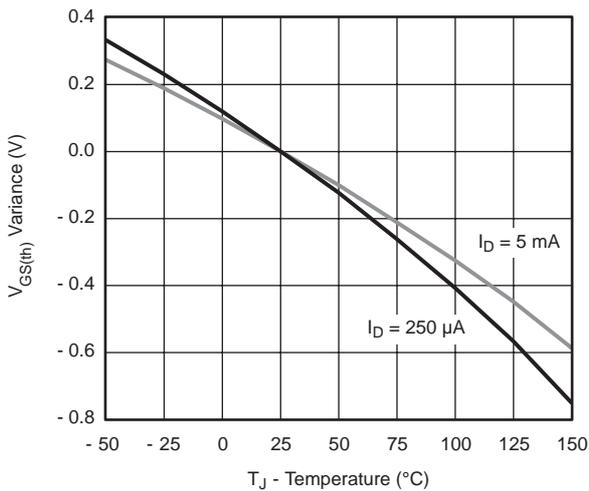
**MOSFET TYPICAL CHARACTERISTICS (25°C, unless otherwise noted)**



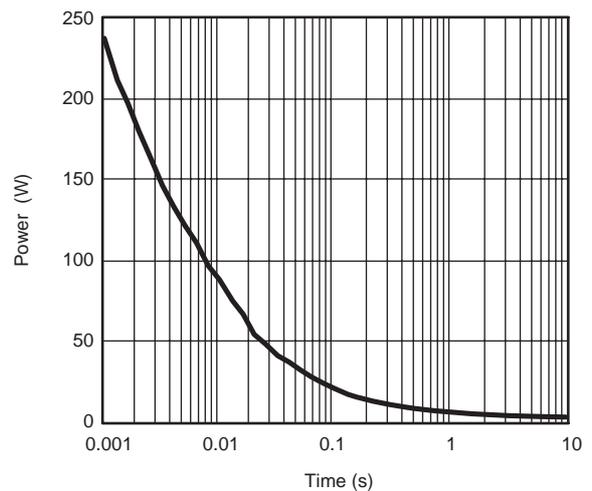
**Source-Drain Diode Forward Voltage**



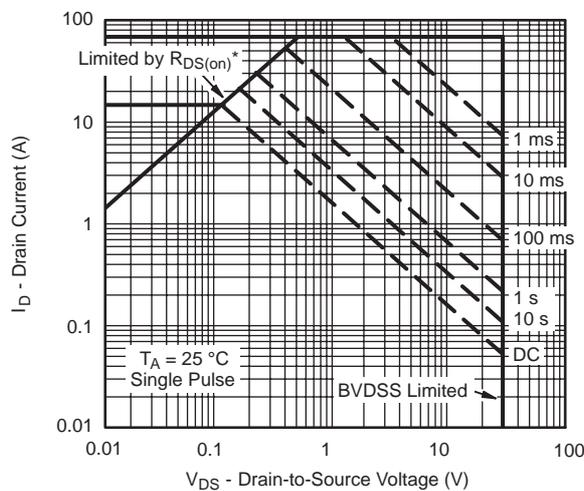
**On-Resistance vs. Gate-to-Source Voltage**



**Threshold Voltage**



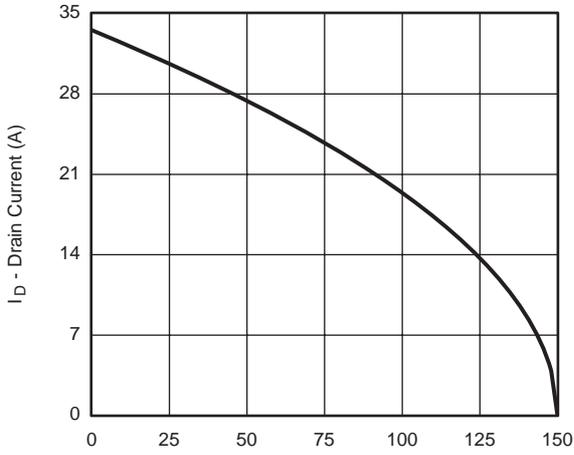
**Single Pulse Power**



\*  $V_{GS} >$  minimum  $V_{GS}$  at which  $R_{DS(on)}$  is specified

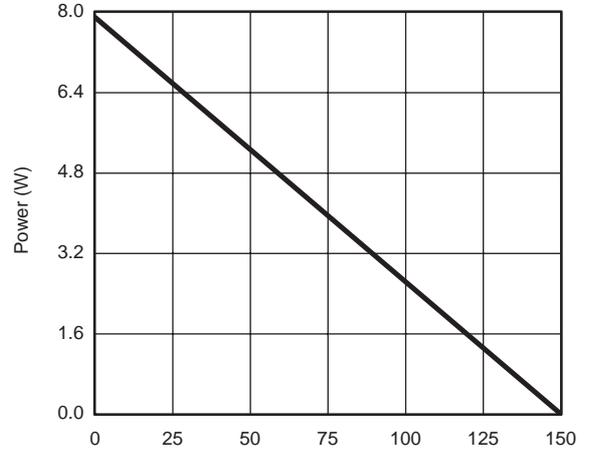
**Safe Operating Area, Junction-to-Ambient**

**MOSFET TYPICAL CHARACTERISTICS (25°C, unless otherwise noted)**



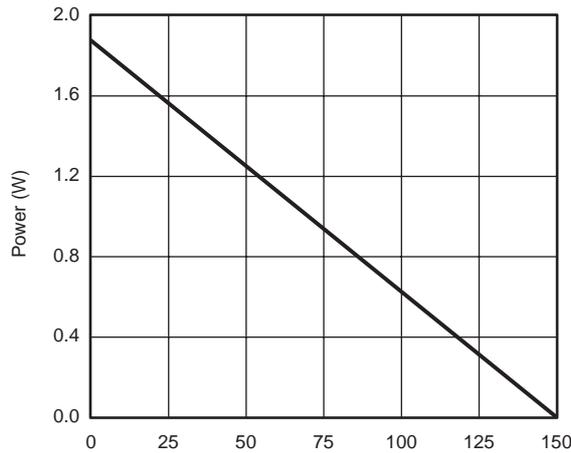
T<sub>C</sub> - Case Temperature (°C)

**Current Derating\***



T<sub>C</sub> - Case Temperature (°C)

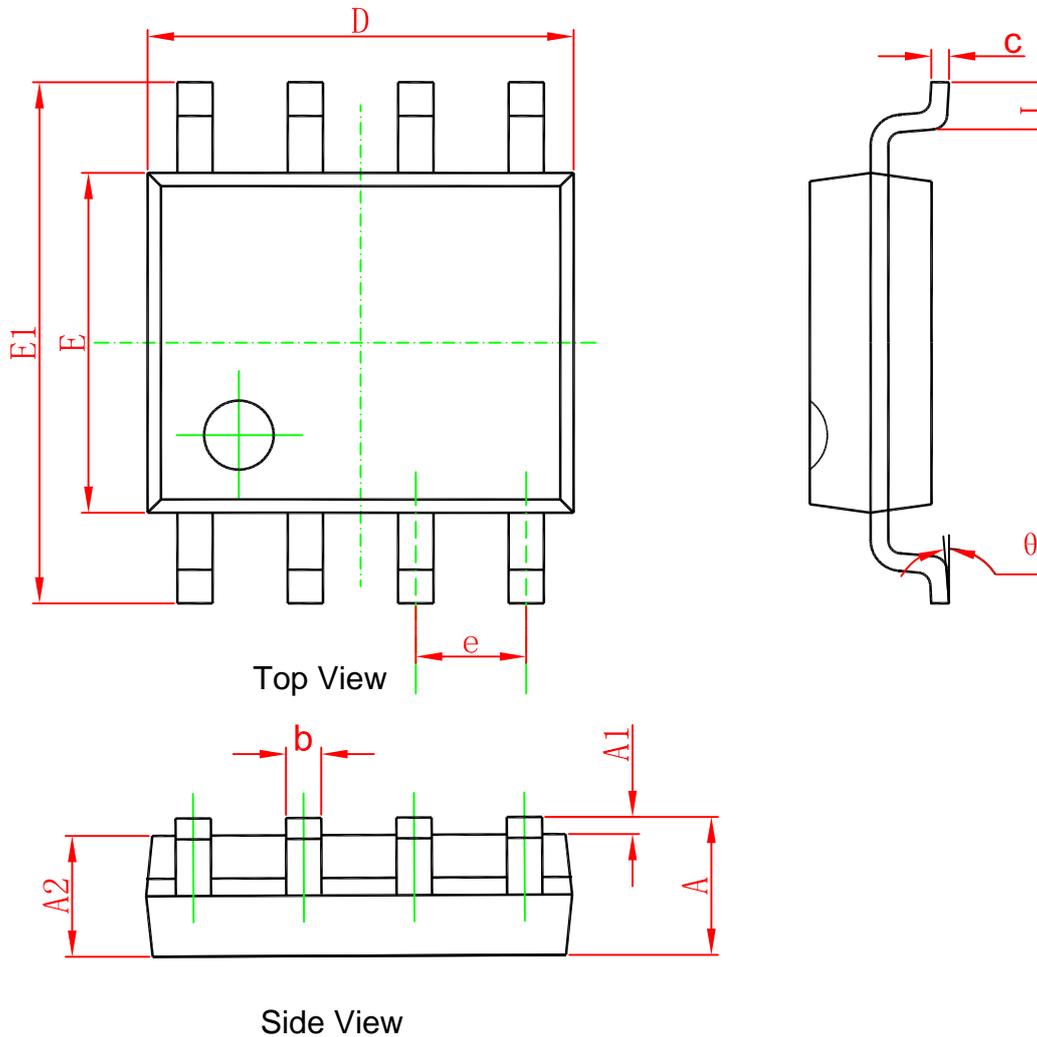
**Power Derating, Junction-to-Foot**



T<sub>A</sub> - Ambient Temperature (°C)

**Power, Junction-to-Ambient**

## SOP-8L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270 (BSC)		0.050 (BSC)	
L	0.400	1.270	0.016	0.050
$\theta$	0°	8°	0°	8°